

FUKUCOM COMPANY LTD.

福靈有限公司

FLAT P, 3/F., EVEREST INDUSTRIAL CENTRE, 396 KWUN TONG ROAD, KWUN TONG, KOWLOON, HONG KONG.

TEL: 852-2790 0314 FAX: 852-2790 0206

BAV99W

HIGH-SPEED DOUBLE SWITCHING DIODE





SOT-323 Plastic Package

Marking Code: A7

Absolute Maximum Ratings (T_a = 25 °C)

Parameter		Symbol	Value	Unit
Repetitive Peak Reverse Voltage		V_{RRM}	85	V
Continuous Reverse Voltage		V_R	75	V
Continuous Forward Current				
	Single Diode Load 1)	I _F	150	mA
	Double Diode Load 1)		130	
Repetitive Peak Forward Current		I _{FRM}	500	mA
Non-repetitive Peak Forward Current				
Square Wave; T _j = 25 °C Prior to Surge	at t = 1 μs	I _{FSM}	4	A
	at t = 1 ms		1	
	at t = 1 s		0.5	
Total Power Dissipation		P _{tot}	200	mW
Junction Temperature		T _j	150	°C
Storage Temperature Range		T _{stg}	-65 to +150	°C
Thermal Resistance from Junction to Ambient 1)		R _{th j-a}	625	K/W

¹⁾ Device mounted on an FR4 printed-circuit board.

Characteristics at T_j = 25°C

Parameter	Symbol	Max.	Unit
Forward Voltage at $I_F = 1$ mA at $I_F = 10$ mA at $I_F = 50$ mA at $I_F = 150$ mA	V _F	0.715 0.855 1 1.25	V
Reverse Current at $V_R = 25 \text{ V}$ at $V_R = 75 \text{ V}$ at $V_R = 25 \text{ V}$, $T_j = 150 \text{ °C}$ at $V_R = 75 \text{ V}$, $T_j = 150 \text{ °C}$	I _R	30 1 30 50	nA µA µA µA
Diode Capacitance at f = 1 MHz; $V_R = 0$	C _d	1.5	pF
Reverse Recovery Time at I_F = 10 mA to I_R = 10 mA, R_L = 100 Ω ; measured at I_R = 1 mA	t _{rr}	4	ns
Forward Recovery Voltage at I _F = 10mA, t _r = 20 ns	V_{fr}	1.75	V





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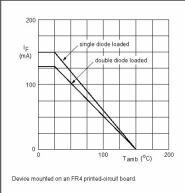
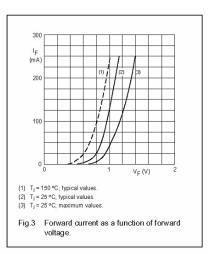
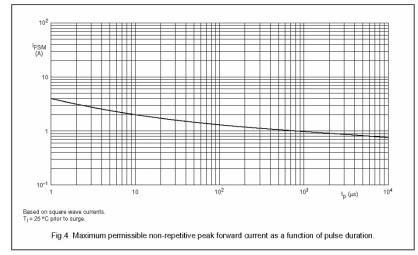
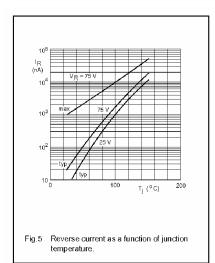
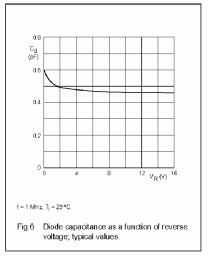


Fig.2 Maximum permissible continuous forward current as a function of ambient temperature.











Dated: 12/01/2006